

7. (amended) A device according to any one of Claims 1, wherein the substrate comprises polymer material.

92 8. (amended) A device according to any one of Claims 1, wherein the areas of weakness extend as lines of weakness between the areas of the substrate carrying the semiconductor devices.

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93 10. (amended) A device according to any one of Claims 1, wherein the discrete areas of the substrate carrying the semiconductor devices are thicker than the remaining areas of substrate.

11. (amended) A device according to claim 1, wherein the semiconductor devices each comprise a semiconductor film formed into an island.

12. (amended) A device according to claim 1, wherein the semiconductor devices comprises thin film transistors.

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13. (amended) A device according to claim 1, wherein the device comprises an active matrix display devices having an array of display pixels and in which each semiconductor device is connected to a respective pixel electrode carried on the substrate.